

N-channel 100V - 0.025Ω - 50A TO-220 / DPAK
Low gate charge STripFET™ II Power MOSFET

Features

| Type | V _{DSS} | R _{DS(on)} Max | I _D |
|-----------|------------------|-------------------------|----------------|
| STD40NF10 | 100V | <0.028Ω | 50A |
| STP40NF10 | 100V | <0.028Ω | 50A |

- Exceptional dv/dt capability
- Low gate charge
- 100% avalanche tested

Application

- Switching applications

Description

This Power MOSFET is the latest development of STMicroelectronics unique "single feature size" strip-based process. The resulting transistor shows extremely high packing density for low on-resistance, rugged avalanche characteristics and less critical alignment steps allowing remarkable manufacturing reproducibility.

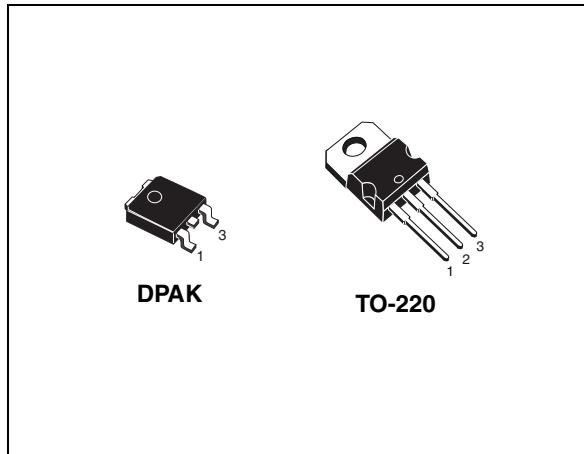


Figure 1. Internal schematic diagram

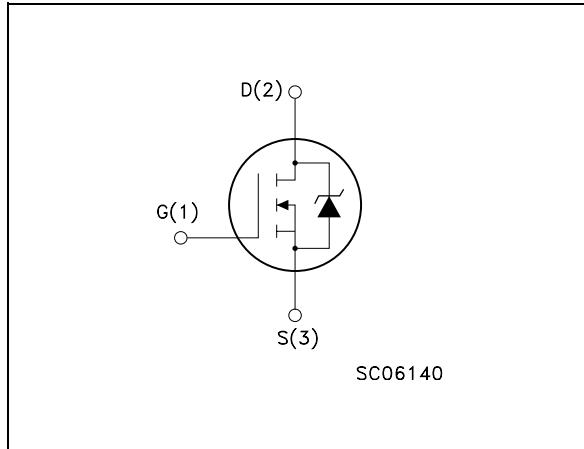


Table 1. Device summary

| Order codes | Marking | Package | Packaging |
|-------------|---------|---------|-------------|
| STP40NF10 | P40NF10 | TO-220 | Tube |
| STD40NF10 | D40NF10 | DPAK | Tape & reel |

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1 Electrical ratings

Table 2. Absolute maximum ratings

| Symbol | Parameter | Value | | Unit |
|----------------|---------------------------------------------------------|-------------|----------|---------------------|
| | | TO-220 | DPAK | |
| V_{DS} | Drain-source voltage ($v_{GS} = 0$) | 100 | | V |
| V_{GS} | Gate- source voltage | | ± 20 | V |
| $I_D^{(1)}$ | Drain current (continuous) at $T_C = 25^\circ\text{C}$ | 50 | | A |
| I_D | Drain current (continuous) at $T_C = 100^\circ\text{C}$ | 35 | | A |
| $I_{DM}^{(2)}$ | Drain current (pulsed) | 200 | | A |
| P_{TOT} | Total dissipation at $T_C = 25^\circ\text{C}$ | 150 | 125 | W |
| | Derating factor | 1 | 0.83 | W/ $^\circ\text{C}$ |
| $dv/dt^{(3)}$ | Peak diode recovery voltage slope | 27 | | V/ns |
| $E_{AS}^{(4)}$ | Single pulse avalanche energy | 385 | | mJ |
| T_{stg} | Storage temperature | – 55 to 175 | | $^\circ\text{C}$ |
| T_j | Max. operating junction temperature | | | |

1. Limited by wire bonding
2. Pulse width limited by safe operating area
3. $I_{SD} \leq 50\text{A}$, $di/dt \leq 600\text{A}/\mu\text{s}$, $V_{DD} \leq V_{(BR)DSS}$, $T_j \leq T_{JMAX}$.
4. Starting $T_j = 25^\circ\text{C}$, $I_D = 50\text{A}$, $V_{DD} = 25\text{V}$

Table 3. Thermal data

| Symbol | Parameter | Value | | Unit |
|----------------|------------------------------------------------|--------|------|--------------------|
| | | TO-220 | DPAK | |
| $R_{thj-case}$ | Thermal resistance junction-case Max | 1 | 1.2 | $^\circ\text{C/W}$ |
| R_{thj-a} | Thermal resistance junction-ambient Max | 62.5 | | $^\circ\text{C/W}$ |
| T_I | Maximum lead temperature for soldering purpose | 300 | | $^\circ\text{C}$ |

2 Electrical characteristics

($T_{CASE}=25^\circ\text{C}$ unless otherwise specified)

Table 4. On/off states

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|---------------------|-----------------------------------------------------|---------------------------------------------------------------------------------------|------|-------|-----------|--------------------------------|
| $V_{(BR)DSS}$ | Drain-source Breakdown voltage | $I_D = 250 \mu\text{A}, V_{GS} = 0$ | 100 | | | V |
| I_{DSS} | Zero gate voltage Drain current ($V_{GS} = 0$) | $V_{DS} = \text{Max rating}$ $V_{DS} = \text{Max rating}, T_C = 125^\circ\text{C}$ | | | 1 10 | μA μA |
| I_{GSS} | Gate-body leakage current ($V_{DS} = 0$) | $V_{GS} = \pm 20\text{V}$ | | | ± 100 | nA |
| $V_{GS(\text{th})}$ | Gate threshold voltage | $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$ | 2 | 3 | 4 | V |
| $R_{DS(\text{on})}$ | Static drain-source on resistance | $V_{GS} = 10\text{V}, I_D = 25\text{A}$ | | 0.025 | 0.028 | Ω |

Table 5. Dynamic

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|----------------|------------------------------|------------------------------------------------------------|------|------|------|------|
| $g_{fs}^{(1)}$ | Forward transconductance | $V_{DS} = 15\text{V}, I_D = 28\text{A}$ | | 22 | | s |
| C_{iss} | Input capacitance | | | 2180 | | pF |
| C_{oss} | Output capacitance | $V_{DS} = 25\text{V}, f = 1 \text{ MHz}$, $V_{GS} = 0$ | | 298 | | pF |
| C_{rss} | Reverse transfer capacitance | | | 83.7 | | pF |
| Q_g | Total gate charge | $V_{DD} = 50\text{V}, I_D = 40\text{A}$ | | 46.5 | | nC |
| Q_{gs} | Gate-source charge | $V_{GS} = 10\text{V}$ | | 13.3 | | nC |
| Q_{gd} | Gate-drain charge | (see Figure 17) | | 17.5 | 22.5 | nC |

1. Pulsed: Pulse duration = 300 μs , duty cycle 1.5.

Table 6. Switching times

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|-----------------------|----------------------------------|--------------------------------------------------------------------------------------------------------|------|----------|------|----------|
| $t_{d(on)}$ t_r | Turn-on delay time Rise time | $V_{DD} = 50\text{V}, I_D = 25\text{A}$ $R_G = 4.7\Omega, V_{GS} = 10\text{V}$ (see Figure 16) | | 21 46 | | ns ns |
| $t_{d(off)}$ t_f | Turn-off-delay time Fall time | $V_{DD} = 27\text{V}, I_D = 40\text{A}$, $R_G = 4.7\Omega, V_{GS} = 10\text{V}$ (see Figure 16) | | 54 13 | | ns ns |

Table 7. Source drain diode

| Symbol | Parameter | Test conditions | Min. | Typ. | Max | Unit |
|-----------------------------------|------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------|------|------------------|-----|---------------|
| I_{SD} $I_{SDM}^{(1)}$ | Source-drain current | | | | 80 | A |
| | Source-drain current (pulsed) | | | | 320 | A |
| $V_{SD}^{(2)}$ | Forward on voltage | $I_{SD} = 50A, V_{GS} = 0$ | | | 1.5 | V |
| t_{rr} Q_{rr} I_{RRM} | Reverse recovery time Reverse recovery charge Reverse recovery current | $I_{SD} = 50A, V_{DD} = 25V$ $di/dt = 100A/\mu s$, $T_j = 150^\circ C$ (see Figure 18) | | 80 250 6.4 | | ns nC A |

1. Pulse width limited by safe operating area.
 2. Pulsed: Pulse duration = 300 μs , duty cycle 1.5%

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area for TO-220

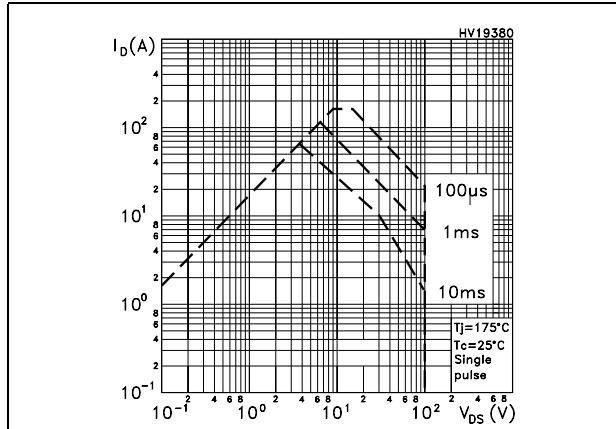


Figure 3. Thermal impedance for TO-220

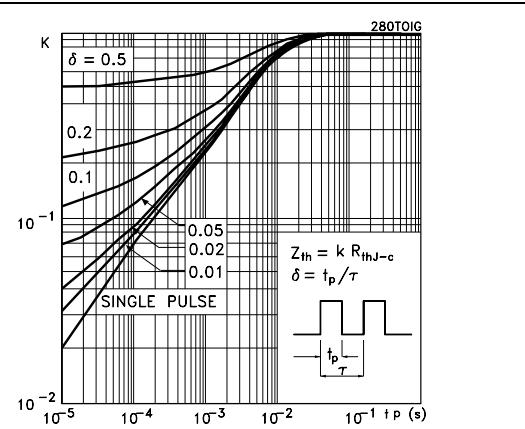


Figure 4. Safe operating area for DPAK

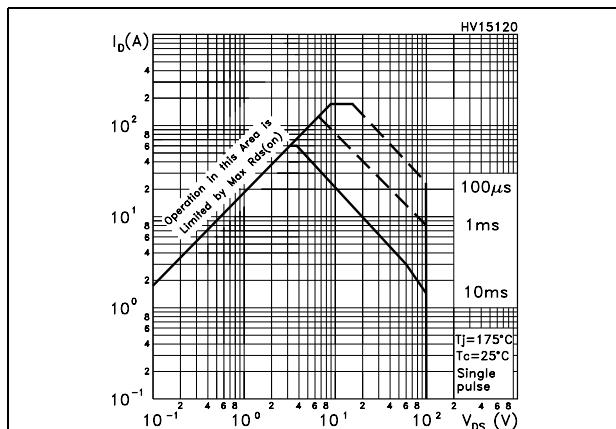


Figure 5. Thermal impedance for DPAK

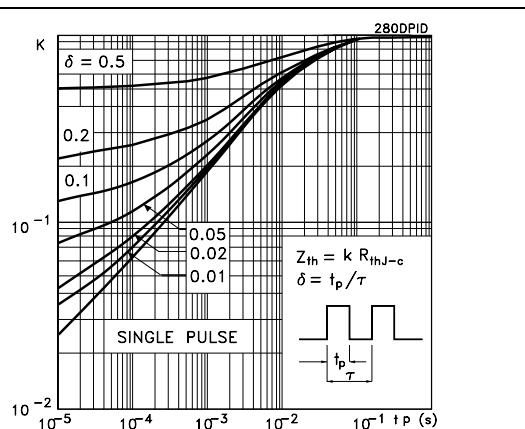


Figure 6. Output characteristics

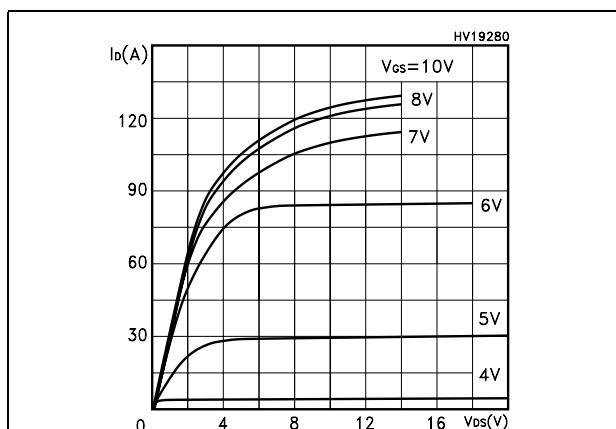


Figure 7. Transfer characteristics

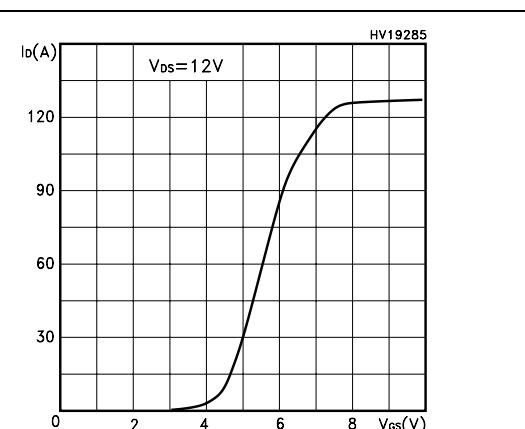


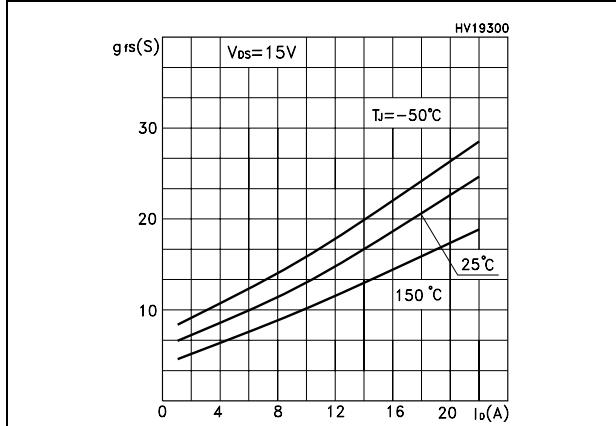
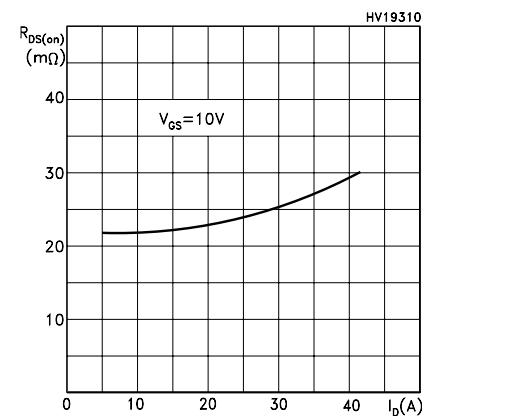
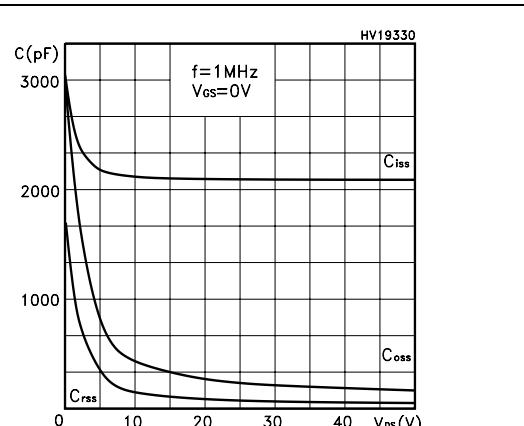
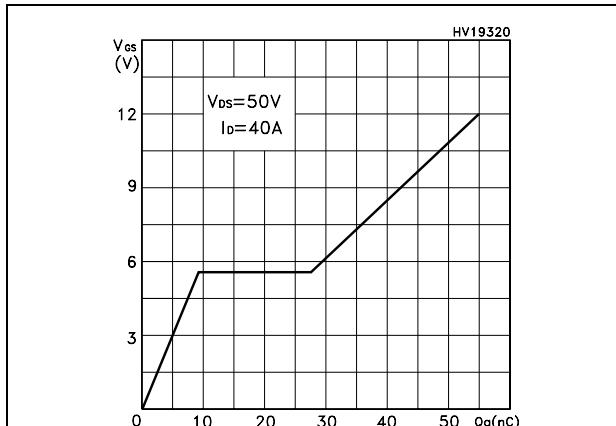
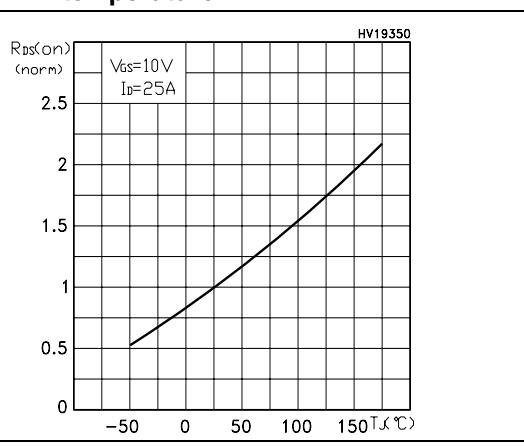
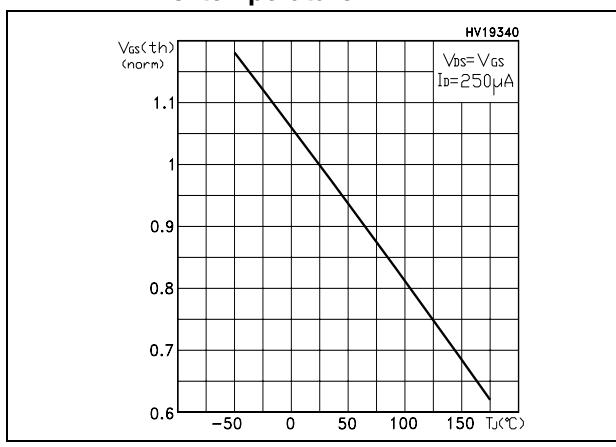
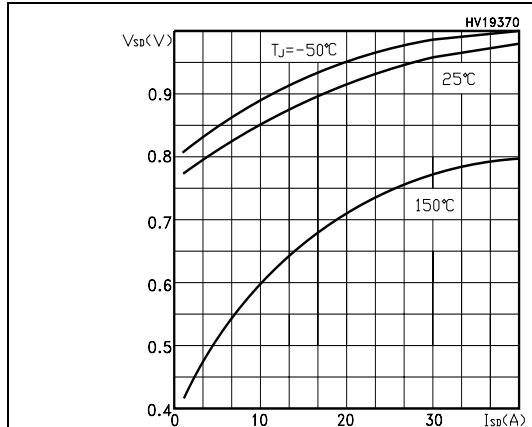
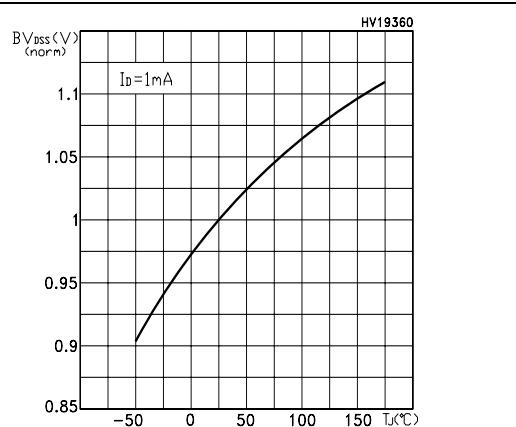
Figure 8. Transconductance**Figure 9. Static drain-source on resistance****Figure 10. Gate charge vs. gate-source voltage** **Figure 11. Capacitance variations****Figure 12. Normalized gate threshold voltage vs. temperature****Figure 13. Normalized on resistance vs. temperature**

Figure 14. Source-drain diode forward characteristics**Figure 15. Normalized breakdown voltage vs. t_j** 

3 Test circuit

Figure 16. Switching times test circuit for resistive load

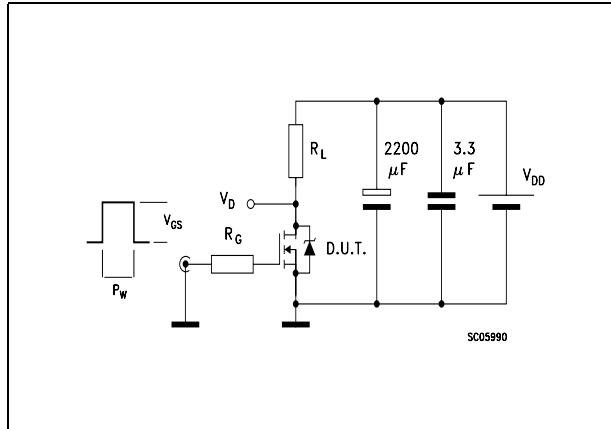


Figure 17. Gate charge test circuit

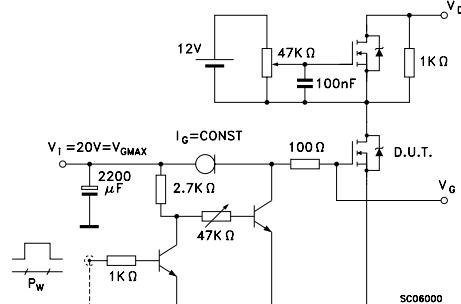


Figure 18. Test circuit for inductive load switching and diode recovery times

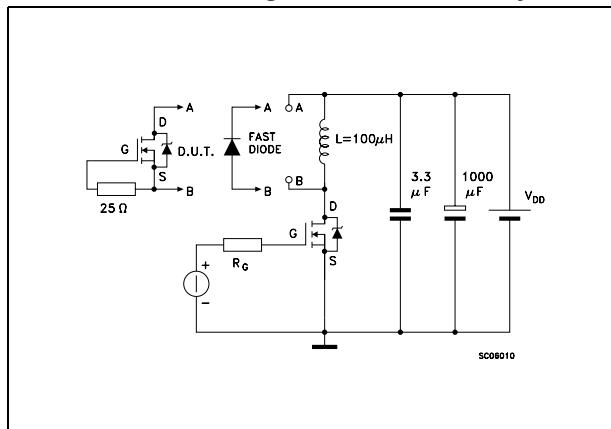


Figure 19. Unclamped Inductive load test circuit

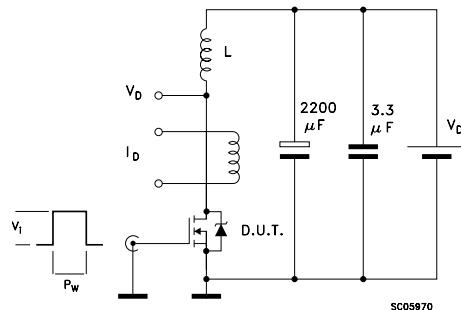


Figure 20. Unclamped inductive waveform

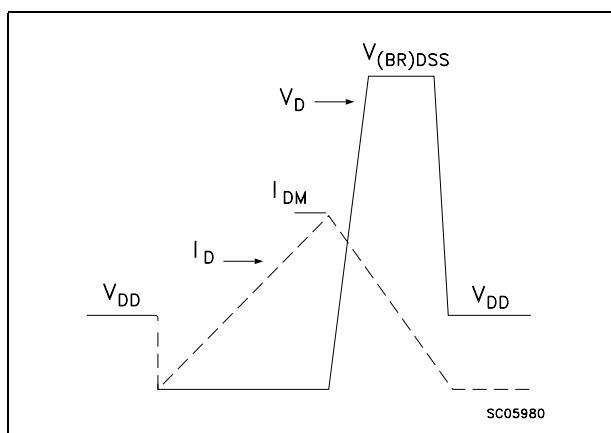
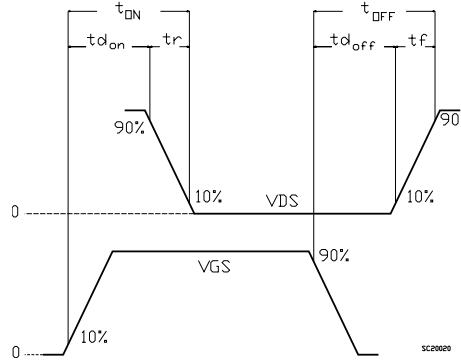


Figure 21. Switching time waveform

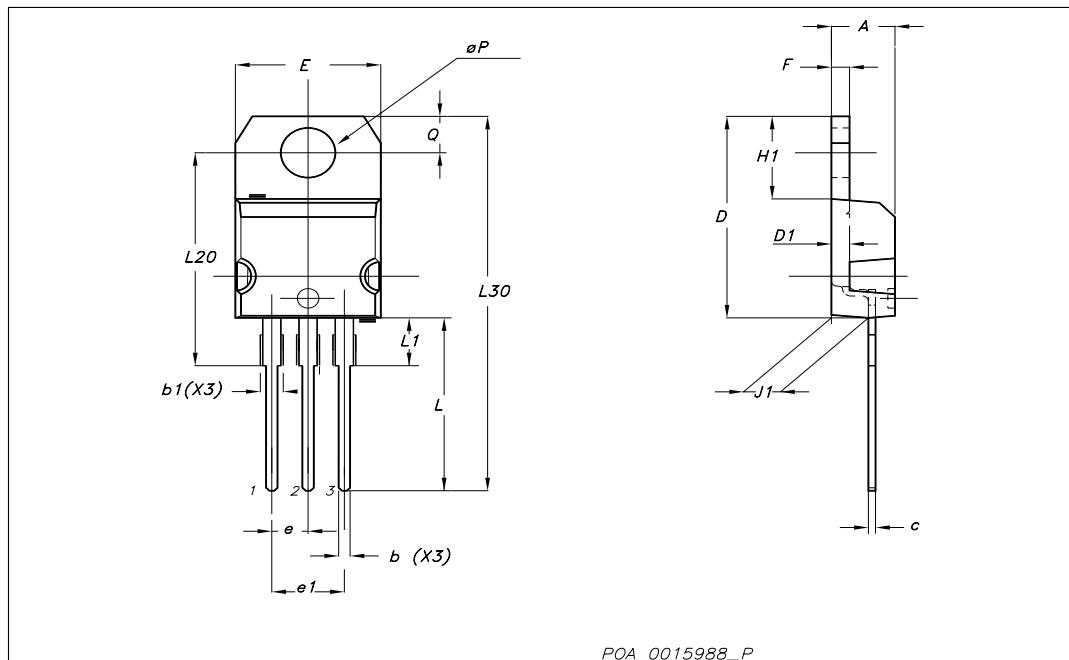


4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at : www.st.com

TO-220 mechanical data

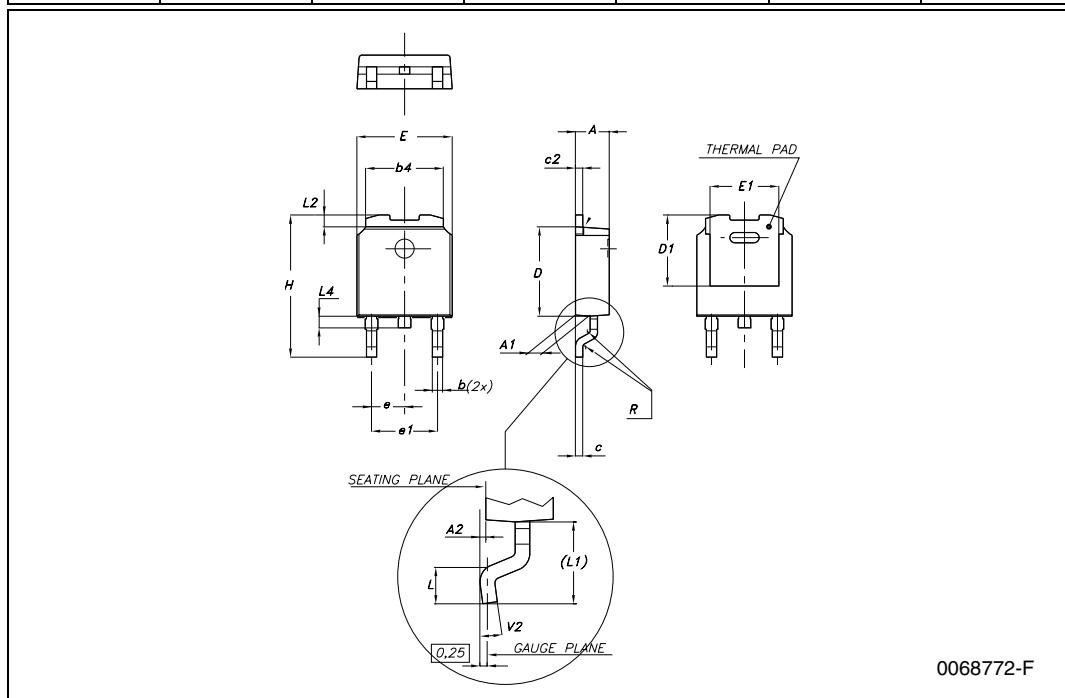
| Dim | mm | | | inch | | |
|-----|-------|-------|-------|-------|-------|-------|
| | Min | Typ | Max | Min | Typ | Max |
| A | 4.40 | | 4.60 | 0.173 | | 0.181 |
| b | 0.61 | | 0.88 | 0.024 | | 0.034 |
| b1 | 1.14 | | 1.70 | 0.044 | | 0.066 |
| c | 0.49 | | 0.70 | 0.019 | | 0.027 |
| D | 15.25 | | 15.75 | 0.6 | | 0.62 |
| D1 | | 1.27 | | | 0.050 | |
| E | 10 | | 10.40 | 0.393 | | 0.409 |
| e | 2.40 | | 2.70 | 0.094 | | 0.106 |
| e1 | 4.95 | | 5.15 | 0.194 | | 0.202 |
| F | 1.23 | | 1.32 | 0.048 | | 0.051 |
| H1 | 6.20 | | 6.60 | 0.244 | | 0.256 |
| J1 | 2.40 | | 2.72 | 0.094 | | 0.107 |
| L | 13 | | 14 | 0.511 | | 0.551 |
| L1 | 3.50 | | 3.93 | 0.137 | | 0.154 |
| L20 | | 16.40 | | | 0.645 | |
| L30 | | 28.90 | | | 1.137 | |
| ØP | 3.75 | | 3.85 | 0.147 | | 0.151 |
| Q | 2.65 | | 2.95 | 0.104 | | 0.116 |



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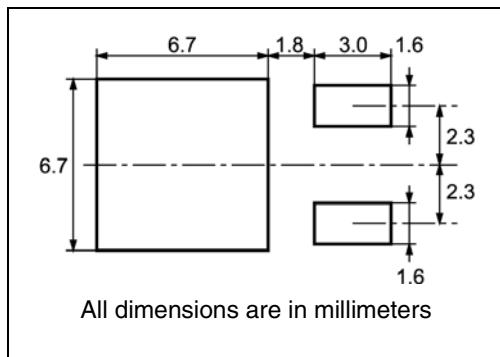
DPAK MECHANICAL DATA

| DIM. | mm. | | | inch | | |
|------|------|------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 2.2 | | 2.4 | 0.086 | | 0.094 |
| A1 | 0.9 | | 1.1 | 0.035 | | 0.043 |
| A2 | 0.03 | | 0.23 | 0.001 | | 0.009 |
| B | 0.64 | | 0.9 | 0.025 | | 0.035 |
| b4 | 5.2 | | 5.4 | 0.204 | | 0.212 |
| C | 0.45 | | 0.6 | 0.017 | | 0.023 |
| C2 | 0.48 | | 0.6 | 0.019 | | 0.023 |
| D | 6 | | 6.2 | 0.236 | | 0.244 |
| D1 | | 5.1 | | | 0.200 | |
| E | 6.4 | | 6.6 | 0.252 | | 0.260 |
| E1 | | 4.7 | | | 0.185 | |
| e | | 2.28 | | | 0.090 | |
| e1 | 4.4 | | 4.6 | 0.173 | | 0.181 |
| H | 9.35 | | 10.1 | 0.368 | | 0.397 |
| L | 1 | | | 0.039 | | |
| (L1) | | 2.8 | | | 0.110 | |
| L2 | | 0.8 | | | 0.031 | |
| L4 | 0.6 | | 1 | 0.023 | | 0.039 |
| R | | 0.2 | | | 0.008 | |
| V2 | 0° | | 8° | 0° | | 8° |



5 Packaging mechanical data

DPAK FOOTPRINT



TAPE AND REEL SHIPMENT

| REEL MECHANICAL DATA | | | | |
|----------------------|------|------|-------|--------|
| DIM. | mm | | inch | |
| | MIN. | MAX. | MIN. | MAX. |
| A | | | 330 | 12.992 |
| B | 1.5 | | 0.059 | |
| C | 12.8 | 13.2 | 0.504 | 0.520 |
| D | 20.2 | | 0.795 | |
| G | 16.4 | 18.4 | 0.645 | 0.724 |
| N | 50 | | 1.968 | |
| T | | 22.4 | | 0.881 |

| TAPE MECHANICAL DATA | | BASE QTY | | BULK QTY | |
|----------------------|------|----------|-------|----------|--|
| DIM. | mm | | inch | | |
| | MIN. | MAX. | MIN. | MAX. | |
| A0 | 6.8 | 7 | 0.267 | 0.275 | |
| B0 | 10.4 | 10.6 | 0.409 | 0.417 | |
| B1 | | 12.1 | | 0.476 | |
| D | 1.5 | 1.6 | 0.059 | 0.063 | |
| D1 | 1.5 | | 0.059 | | |
| E | 1.65 | 1.85 | 0.065 | 0.073 | |
| F | 7.4 | 7.6 | 0.291 | 0.299 | |
| K0 | 2.55 | 2.75 | 0.100 | 0.108 | |
| P0 | 3.9 | 4.1 | 0.153 | 0.161 | |
| P1 | 7.9 | 8.1 | 0.311 | 0.319 | |
| P2 | 1.9 | 2.1 | 0.075 | 0.082 | |
| R | 40 | | 1.574 | | |
| W | 15.7 | 16.3 | 0.618 | 0.641 | |

6 Revision history

Table 8. Document revision history

| Date | Revision | Changes |
|-------------|----------|-------------------------------------------|
| 16-Dec-2004 | 1 | First version. |
| 17-Aug-2006 | 2 | The document has been reformatted. |
| 31-Jan-2007 | 3 | Typo mistake on Table 2 . |
| 19-Sep-2007 | 4 | Added DPAK |

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